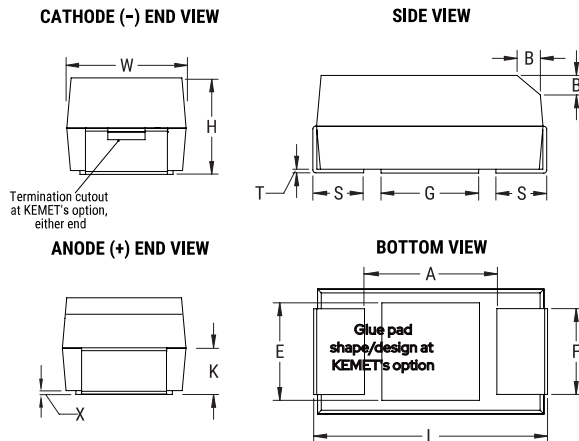


T495C475M035AH4095

Aliases (DLA Drawing 95158-29MH)

T495 HRA, Tantalum, MnO₂ Tantalum, HRA, 4.7 uF, 20%, 35 VDC, SMD, MnO₂, Molded, Low ESR, High Reliability, N/A, 600 mOhms, 6032, 2.8 mm, 1.3 mm



Click [here](#) for the 3D model.

General Information

Series	T495 HRA
Dielectric	MnO ₂ Tantalum
Style	SMD Chip
Description	SMD, MnO ₂ , Molded, Low ESR, High Reliability
Features	Low ESR, High Reliability
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov/
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	224.48 mg
MSL	1

Dimensions

L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
A	3.1mm MIN
B	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
K	1.4mm +/-0.2mm
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

Specifications

Capacitance	4.7 uF
Tolerance	20%
Voltage DC	35 VDC (85C), 23.45 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	600 mOhms (100kHz 25C)
Ripple Current	428 mA (rms, 100kHz 25C), 385 mA (rms, 100kHz 85C), 171 mA (rms, 100kHz 125C)
Leakage Current	1.7 uA (5min 25°C)
Testing and Reliability	Tested To Meet The Established Reliability

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.